Lead fluoride Cherenkov detector read out by avalanche photodiodes for measuring the intensities of pulsed antiproton beams

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Abstract

A Cherenkov detector based on an array of five lead fluoride (β -PbF₂) crystals of size 30 mm×30 mm×160 mm read out by reverse-type avalanche photodiodes (APD's) of active area $10 \text{ mm} \times 10 \text{ mm}$ was used to measure the flux of secondary particles emerging from the annihilation of pulsed beams of antiprotons at the Antiproton Decelerator of CERN. We compared the relative photon yields of radiators made of β -PbF₂, fused silica, UV-transparent acrylic, lead glass, and a lead-free, high-refractive-index glass. Some p-i-n photodiodes were also used for the readout, but the output signals were dominated by the nuclear counter effect (NCE) of secondary particles traversing the 300 μ m thick depletion regions of the photodiodes. Smaller NCE were observed with the APD's, as the maximum electronic gain in them occurred predominately for electron-ion pairs that were generated in the thin p-type semiconductor layer that proceeded the p-n junction of high electric field where amplification took place.

Keywords: Lead fluoride, Cherenkov detector, antiproton, avalanche photodiode

Abstract A Cherenkov detector based on an array of five lead fluorid-by reverse-type avalanche photodiodes (APD's) of active ar particles emerging from the annihilation of pulsed beams compared the relative photon yields of radiators made of *j* a lead-free, high-refractive-index glass. Some *p-i-n* photod were dominated by the nuclear counter effect (NCE) of seco of the photodiodes. Smaller NCE were observed with the predominately for electron-ion pairs that were generated in junction of high electric field where amplification took place *Keywords:* Lead fluoride, Cherenkov detector, antiproton, **1. Introduction** The Atomic Spectroscopy and Collisions Using Slow Antiprotons (ASACUSA) collaboration has recently mea-sured the cross sections σ_{tot}^A of antiprotons with an inci-dent kinetic energy $E \sim 5.3$ MeV annihilating via in-flight nuclear reactions in carbon, Mylar, nickel, tin, and plat-inum targets [1, 2, 3]. Measurements of σ_{tot}^A were also attempted on $E = 130 \pm 10$ keV antiprotons annihilating in carbon, palladium, and platinum target foils of sub-100 nm thicknesses [4, 5, 6]. These experiments were carried out at the Antiproton Decelerator (AD) of CERN using $\Delta t = 50-120$ ns long pulsed beams that contained between $N_{\overline{p}} = 2 \times 10^5$ and 5×10^6 antiprotons. The arrival of in-dividual antiprotons at the target could not be resolved. We instead determined the relative intensity and temporal structure of the beam by using acrylic Cherenkov detectors to measure the flux of secondary charged particles (mostly charged pions, muons, and electrons) that emerged from the simultaneous annihilations in the apparatus. These past experiments utilized fine-mesh photomultiplier tubes [7] which had signal responses that were highly linear to read out the Cherenkov radiators. In this paper, we describe a different Cherenkov detectors the the theories of the use of the two the duration to the second the cherenkov detectors. In this paper, we describe a differen read out the Cherenkov radiators.

In this paper, we describe a different Cherenkov detector that consisted of an array of five lead fluoride crystals in the cubic phase $(\beta$ -PbF₂) [8, 9, 10, 11] of size 30 mm×30 mm×160 mm. The arrival of antiproton pulses at the experimental target produced an intense flash of Cherenkov light in each crystal; this was measured by a reverse-type [12, 13, 14, 15, 16] avalanche photodiode (APD) of active area 10 mm $\times 10$ mm. These crystals are sensitive to both the charged secondary particles and γ -rays [7] that emerge from antiproton annihilations, and are expected to have a higher light yield compared to Cherenkov detectors based on acrylic radiators of the same size. Other advantages of the detector include its compact size and insensitivity to magnetic fields, which may allow its use in experiments involving magnetic Penning traps within the physics program of the AD [17]. The radiation-hard nature of the β -PbF₂ crystals may allow their use in measuring high-intensity beams of electrons in laser spectroscopy experiments of metastable pionic helium atoms [18]. We compared the light yields of Cherenkov radiators made of β -PbF₂, fused silica, acrylic, lead glass, and a leadfree, high-refractive index glass against antiproton annihilations. We also attempted to use p-i-n photodiodes [19] for the readout, but the waveform of the output signals contained a dominant background that arose from the nuclear counter effect (NCE) of secondary particles traversing the $\sim 300 \ \mu m$ thick depletion regions of these detectors [20, 21]. The relative size of the NCE was much smaller in reverse-type APD's, because the maximum electronic gain occurred predominantly for those electron-ion pairs that were generated in the thin *p*-type semiconductor layer that proceeded the p-n junction of high electric field where amplification took place [12, 13, 14, 15, 16, 21]. The detec-

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Table 1: Specifications of the avalanche and *p-i-n* photodiodes used in this study: their active areas, effective thicknesses against ionizing radiation, terminal capacitances, cutoff frequencies of the output signals, and wavelength ranges over which the photodiodes retain sensitivity.

Photodiode	Area	Eff. thickness	Capacitance	Cutoff freq.	Spect. response	
	$(mm \times mm)$	(μm)	(pF)	(MHz)	(nm)	
S8664-1010 (APD)	10×10	~ 5	270	~11	320-1000	
S3204-08 (<i>p-i-n</i>)	18×18	300	130	20	340 - 1100	
S3590-08 (<i>p-i-n</i>)	10×10	300	40	40	340 - 1100	

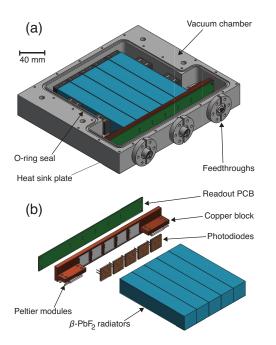


Figure 1: (a) Layout of the Cherenkov detector hermetically sealed in an aluminum chamber. (b) Details of the β -PbF₂ radiator, photodiodes, copper block, printed circuit board (PCB), and Peltier thermoelectric modules.

tor was recently used in an experiment to determine the cross section σ_{tot}^A of 5.3 MeV antiprotons annihilating in a carbon target [3].

Since the 2000's, β -PbF₂ crystals have been used in electromagnetic calorimeters with high timing resolutions. The A4 collaboration used 1022 crystals of lengths between l = 150 and 180 mm, in a parity-violating, electronscattering experiment that was carried out at the Mainz Microtron (MAMI) facility [11, 22]. Each crystal was read out by a photomultiplier tube with 10-stage, line focusing dynodes. The muon g-2 experiment at Fermilab utilized ~ 1300 crystals of size 25 mm $\times 25$ mm $\times 140$ mm, which were read out by arrays of 16 silicon photomultipliers (SiPM's) of active area $12 \text{ mm} \times 12 \text{ mm}$ [23, 24]. Positrons of energy $E \sim 2$ GeV that emerge from μ^+ decays in a storage ring were reconstructed with an energy resolution of < 5% and a timing resolution $\Delta t < 100$ ps. A positron annihilation lifetime spectroscopy (PALS) experiment used the β -PbF₂ crystals to detect 511 keV gamma nm, radiation hardness (~ 10^4 – 10^5 rad) [8, 26], and a small radiation length ($\ell_r = 9.3 \text{ mm}$) and Moliere radius $(M_r = 22 \text{ mm})$. On the other hand, the light yield of β -PbF₂ is much smaller than those of scintillators such as lead tungstate (PbWO₄) and thallium activated cesium iodide [CsI(Tl)]. For each MeV of energy deposited in a $\beta\operatorname{-PbF}_2$ crystal, a photomultiplier coupled to it typically detects $\Gamma = 1.5$ –1.9 photoelectrons [11]. It is difficult to grow large ($\ell >> 200$ mm) crystals of high transparency and optical uniformity [27, 28, 29]. It was noted that when oxygen impurities were allowed to diffused into the crystals during their growth, regions that consist of lead oxide, lead fluoro-oxide, or the opaque, orthorhombic phase of lead fluoride (α -PbF₂) were formed. These appeared as scattering centers and inclusions that could reduce the collection efficiency of the Cherenkov light. It has also been reported that when exposed to a high-humidity environment, the surfaces of the crystals changed into a frostywhitish appearance [28, 29].

rays with a timing resolution $\Delta t \sim 3.5$ ns [25].

The advantages of β -PbF₂ crystals include a high re-

fractive index ($n_r = 1.82$) and density ($\rho = 7.77 \text{ g/cm}^3$), significant transmission at ultraviolet wavelengths $\lambda \sim 260$

2. Detector

2.1. Construction

The five β -PbF₂ crystals of size 30 mm×30 mm×160 mm (see Fig. 1) were wrapped in two layers of a polyvinylidene fluoride membrane with 0.45 μ m pores (Millipore Immobilone-P), which constituted a diffusive reflector. A silicon APD of active area 10 mm \times 10 mm (Hamamatsu Photonics S8664-1010, see Table 1) was attached to one end of each crystal. The five APD's in the array were thermally anchored on a 200 mm long copper block using thermal paste (Electrolube HTCP). A two-terminal, temperature-to-voltage transducer (Analog Devices AD590MH) was also glued to the block using an epoxy adhesive that had a high thermal conductivity (Henkel Loctite Stycast 1266). This assembly was cooled to a temperature $T \sim 19$ $^{\circ}C$ with a stability of $\pm 0.1^{\circ}C$, using two Peltier thermoelectric modules (Adaptive ET-03-10-13-RS) of size 30 $mm \times 15 mm$ and cooling power $\sim 6 W$ that were regulated by a proportional-integral-differential controller (Thorlabs TED200C) and a separate 5 W direct current (DC) power

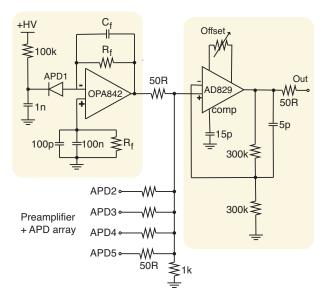


Figure 2: Circuit diagram of the array of five transimpedance preamplifiers of which one channel is shown. The output signals are summed using a resistor network and a driver amplifier. The feedback resistor R_f and capacitor C_f of each preamplifier were adjusted to optimize the timing response and stability of the APD or *p-i-n* photodiode signal.

supply. The electronics for biasing the photodiodes, amplifying the output signals, and providing the low-noise, regulated DC power sources of ± 5 V and ± 15 V were integrated on a four-layered printed circuit board (PCB) of size 30 mm×200 mm. This PCB made of 1.6 mm thick glass epoxy (Panasonic Electronic Works R1705) was also mounted to the copper block using four Teflon standoffs that helped to thermally isolate it from the block.

The detector was housed in a 290 mm×245 mm×50 mm aluminum chamber of wall thickness $t_r = 5$ mm. The chamber was hermetically sealed and purged with nitrogen to prevent condensation on the cooled photodiodes and β -PbF₂ crystals that may arise from the high humidity in the vicinity of the cryogenic target. The chamber also shielded the photodiodes against the electromagnetic interference of frequency range f = 10-200 MHz that was emitted from the AD and radiofrequency quadrupole decelerator (RFQD) [17]. Detector modules which employed silicon *p*-*i*-*n* photodiodes of active area 18 mm×18 mm (S3204-08) or 10 mm×10 mm (S3590-08) instead of the APD were also constructed (Table 1). The photodiodes were protected by thin windows of epoxy resin.

A bias voltage $V_{\rm b} \sim 380$ V was applied to the cathode terminal of each APD through a low-pass filter that consisted of a R = 100 k Ω thin metal film resistor and a C = 1 nF radiofrequency mica capacitor (see Fig. 2). The anode terminals were connected to transimpedance preamplifiers that contained an operational amplifier (Texas Instruments OPA842IDB) with a gain bandwidth product of $f_b = 200$ MHz, input voltage noise 2.6 nV/ $\sqrt{\text{Hz}}$, low distortion, and a DC voltage offset ± 0.3 mV. A feedback

resistor $R_f = 1 \ \mathrm{k}\Omega$ which corresponded to a photocurrentto-voltage conversion ratio $g \sim 10^3 \text{ V/A}$ was chosen to provide the best dynamic range for measuring the Cherenkov signals with typical amplitudes of 20–40 mV. As the APD's had a large terminal capacitance $C_d \sim 270$ pF, a compensating feedback capacitor $C_f = 22 \text{ pF}$ was added to avoid excessive ringing and oscillation of the output signal, and obtain a flat frequency response with a -3dB corner frequency $f_r \sim \sqrt{f_b/2\pi R_f C_d} \sim 6$ MHz. For reading out the S3204-08 *p-i-n* photodiodes of $C_d \sim 130$ pF, the feedback elements were changed to values $R_f = 3 \ \mathrm{k}\Omega$ and $C_f = 12$ pF which provided the best compromise between a higher gain $g \sim 3 \times 10^3$ V/A, corner frequency $f_r \sim 9$ MHz, and the stability of the transimpedance preamplifier. For the smaller *p-i-n* photodiodes (S3590-08) of $C_d \sim 40$ pF, an operational amplifier (OPA843IDB) of larger gain bandwidth product $f_b = 800$ MHz in conjunction with feedback values $R_f = 3 \ \mathrm{k}\Omega$ and $C_f = 2 \ \mathrm{pF}$ were used to obtain a -3dB corner frequency $f_r \sim 20$ MHz.

The output signals of the five transimpedance preamplifiers were summed using a resistor network, and amplified by a non-inverting follower of gain 2 which was based on a bipolar operational amplifier (Analog Devices AD829AR) with an input voltage noise $\sim 1.7 \text{ nV}/\sqrt{\text{Hz}}$. This resulted in an output signal of typical amplitude V = 200-400 mV into a 50 Ω impedance, which was superimposed on a DC offset. The signal was transmitted out of the chamber using a SMA-type coaxial vacuum feedthrough, and its analog waveform recorded by a digital oscilloscope of analog bandwidth f = 4 GHz, digital sampling rate $f_s = 10$ Gs/s, and a vertical resolution of 8 bits (Lecroy Waverunner 640Zi). The ± 5 V and ± 15 V DC power needed for the amplifiers were generated by four linear regulators (Linear Technology LT1965IDD and LT3015IDD) and passed through some electromagnetic interference filters (Murata BNX002). The linear regulators were supplied with source voltages that were adjusted slightly (~ 0.35 V) above their regulated output voltages. This helped to minimize the heat dissipation in the chamber.

2.2. Cherenkov radiators

The β -PbF₂ crystals were grown using the Bridgman method and all surfaces polished by the Shanghai Institute of Ceramics, Chinese Academy of Sciences (SICCAS). The crystals were specified by the manufacturer to be without cracks or scratches longer than 10 mm and deeper than 2 mm, and no inclusions, scattering centers, or microcracks observable with the naked eye. Cherenkov radiators of the same size made of fused silica (CoorsTek T-4040), UV transparent grade acrylic plastic (Nitto Jushi Kogyo Co. Clarex S-0), high transmission grade lead glass (Schott AG SF57HTultra), and Ohara S-TIH53W glass were also manufactured (see Table. 2). The last of these was a leadfree glass with a high refractive index $n_r \sim 1.8$, density $\rho = 3.5$ g/cm³, and partial dispersion of Abbe number

Table 2: Refractive indices, radiation lengths, and measured ultraviolet (UV) cutoff wavelengths of five types of Cherenkov radiator materials used in this work. The UV cutoff wavelengths are approximate values based on the measurements shown in Fig. 3.

Radiator	Refractive index	Density	Radiation length	UV cutoff
		(g/cm^3)	(mm)	(nm)
β -PbF ₂ (lead fluoride)	1.82	7.77	9.3	~ 260
T-4040 (fused silica)	1.49	2.2	~ 120	< 190
Clarex S-0 (acrylic)	1.46	1.18	~ 340	~ 320
SF57HTultra (lead glass)	1.85	5.51	15	~ 390
S-TIH53W	1.84	3.54		~ 400

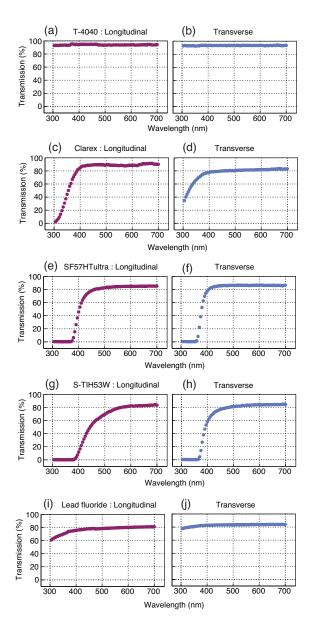


Figure 3: Longitudinal and transverse transmissions of Cherenkov radiators made of fused silica (T-4040), acrylic (Clarex S-0), lead glass (SF57HTultra), and lead free high refractive index glass (S-TIH53W) at wavelengths between $\lambda = 300$ nm and 700 nm measured with a photospectrometer (see text).

 $\nu_d \sim 23.8$. X-ray photoelectron spectroscopy measurements on ground samples of the glass showed that it contained barium, titanium, and niobium oxides. These "eco-friendly" alternatives to conventional flint glass generally have reduced transmission at blue and UV wavelengths. The surfaces of the fused silica, lead glass, and S-TIH53W glass radiators were optically polished to a quality that was specified to be scratch-dig 60-40 and flatness of peak-to-valley $\sim \lambda/2$ wave.

The optical transmissions (Fig. 3) of each radiator along its longitudinal (i.e., long) axis, and at four positions [indicated by arrows labeled T1, T2, T3, and T4 in Fig. 4(a)] parallel to its transverse (short) axis at wavelengths between $\lambda = 300$ and 700 nm were measured using a photospectrometer. The device was of single beam type and included a xenon halide lamp as the light source. No position-dependent variations over T1–T4 were seen in the transverse transmissions of the fused silica, acrylic, lead glass, and S-TIH53W radiators, and so we plotted the typical values for each material in Figs. 3(b), 3(d), 3(f), and 3(h), respectively.

The fused silica radiators [Figs. 3(a)–(b)] showed high transverse and longitudinal transmissions of $T_t \sim T_l \sim$ 94% over the entire range of measured wavelengths. The majority of the losses were caused by the ~ 3% reflections at each glass-to-air interface, whereas the attenuation in the glass was negligible. The transverse and longitudinal transmissions of the acrylic radiator at visible wavelengths $\lambda = 400-700$ nm were slightly lower at $T_t \sim 90\%$ and $T_l \sim$ 80%, respectively [Figs. 3(c)–(d)]. Significant reductions of the transmissions to $T_t \sim 40\%$ and $T_l \sim 15\%$ were seen at a UV wavelength $\lambda \sim 330$ nm.

The lead glass radiators [Fig. 3(e)] retained transmissions of $T_l \sim 82\%$ over the visible wavelengths $\lambda = 490 -$ 700 nm, which rapidly decreased to ~ 40% and ~ 10% at the UV wavelengths $\lambda = 400$ nm and 380 nm, respectively. The transverse transmission [Fig. 3(f)] was somewhat higher: $T_t \sim 83\%$, ~ 40%, and ~ 10% at the respective wavelengths $\lambda = 420 - 700$ nm, 380 nm, and 370 nm. The S-TIH53W radiator had a slightly yellowish color [Figs. 3 (g)–(h)], and the highest absorption among the materials studied here. The longitudinal transmissions at wavelengths $\lambda = 590 - 700$ nm and 405 nm were

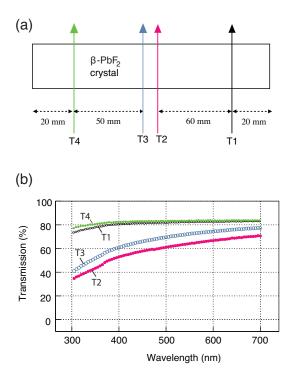


Figure 4: (a) Four paths (indicated by T1–T4) parallel to the transverse axis of the β -PbF₂ crystals where the optical transmissions were measured. (b) Transmissions at wavelengths between $\lambda = 300$ and 700 nm corresponding to each light path.

 $T_l \sim 80\%$ and $\sim 20\%$, respectively. The transverse values at $\lambda = 520 - 700$ nm and 380 nm were $T_t \sim 82\%$ and $\sim 20\%$, respectively.

The UV transmission of the β -PbF₂ crystals were lower compared to fused silica, but higher than the other three materials studied here [Figs. 3(i)–(j)]. Small, white scattering centres along the surfaces of the β -PbF₂ crystals caused significant variations in the optical transmission: in one sample, transmissions of $T_t \sim 74\%$, $\sim 35\%$, $\sim 32\%$, and $\sim 78\%$ were measured at the respective positions T1, T2, T3, and T4 [Fig. 4(b)]. The longitudinal transmission was typically $T_l \sim 80\%$ at visible wavelengths $\lambda = 400-700$ nm, and $T_l \sim 60\%$ at $\lambda = 300$ nm.

2.3. APD's and p-i-n photodiodes

The S8664-1010 silicon APD's [15, 16] (Table 1) of active area 10 mm × 10 mm were previously used to read out CsI(Tl), BGO, and GSO(Ce) scintillators that emit at blue and green wavelengths [14, 30, 31]. The quantum efficiencies specified at wavelengths $\lambda = 330$ nm, 420 nm, and 600 nm were $\varepsilon \sim 45\%$, 70%, and 85%, respectively. The APD's were of the so-called reverse type, where the *p*-*n* junction of high field in which multiplication takes place was typically located about ~ 5 μ m from the illuminated surface of the sensor [12, 13, 14, 15, 16]. Visible photons were absorbed and generated electron-hole pairs within the first few microns of the depletion region. These electrons were collected and underwent multiplication with the highest gain. Although charged particles, X-rays, and neutrons

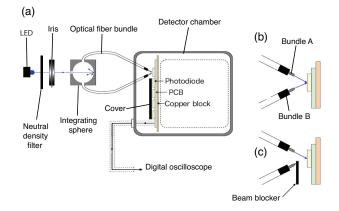


Figure 5: (a) Layout for measuring the linearity response of the photodiode and transimpedance preamplifier combinations, not to scale. Blue light pulses produced by a LED were attenuated by neutral density filters before entering an integrating sphere. The light was extracted from the sphere through a pair of optical fiber bundles. (b) The light emitted from the two fiber bundles A and B were focused onto the surface of one of the photodiodes in the array. The remaining four photodiodes were masked using a sheet of black rubber (see text). (c) For some of the measurements, a sheet of black rubber was used to prevent the light emitted by fiber B from reaching the photodiode.

traversing the APD generated primary ion pairs over the entire width of the photodiode, only those pairs that originated in the thin *p*-type layer preceding the high-field *p*-*n* junction underwent high-gain multiplication. This lead to a small ($t_r < 6 \ \mu$ m) effective thickness of the device with regards to the nuclear counting effect (NCE) against ionizing radiation, which was measured using a ⁹⁰Sr source [14].

The S3204-08 silicon *p-i-n* photodiode, on the other hand, had an active area of 18 mm × 18 mm, depletion layer thickness $t_d = 300 \ \mu\text{m}$, terminal capacitance $C_d \sim$ 130 pF, and sensitivity at wavelengths between $\lambda = 340$ and 1100 nm with a maximum at $\lambda \sim 960$ nm (Table 1). Similar devices have been previously used for CsI(Tl) calorimeter readout [32, 33, 34, 35]. The S3509-08 *p-i-n* photodiode had a smaller active area 10 mm×10 mm and capacitance $C_d \sim 40$ pF, and the highest signal cutoff frequency $f_c = 40$ MHz among the detectors used here.

The signal linearity responses of the three photodiode and transimpedance preamplifier combinations were measured [38, 39] using the setup of Fig. 5(a). A light emitting diode (Thorlabs M450D3) produced a 100 ns long light pulse of emission wavelength $\lambda \sim 450$ nm, power ~ 300 mW, and emission angle $\theta = 120^{\circ}$. The light was attenuated using a pair of variable neutral density filter wheels and an iris, before being coupled into a 51 mm diameter integrating sphere (Thorlabs IS200) that had an internal surface reflectivity of 99%. The propagation direction and polarization of the light was thus randomized. Part of this light was extracted from the sphere through a pair of optical fiber bundles (Thorlabs BF20HSMA01) that each consisted of 7 multimode optical fibers of core diameter $d \sim 550 \ \mu m$ and numerical aperture $N_A = 0.22$. The

fibers were made of fused silica with a high concentration of hydroxyl groups (OH). The intensity of the light emitted from each fiber bundle [indicated by A and B in Fig. 5(b)] was found to be equal to within $\sim 10\%$. The light was expanded using aspheric lenses of focal length $f_l \sim 18 \text{ mm}$ (Thorlabs F280SMA-A) into a 8 mm diameter spot on the surface of one of the photodiodes. The other four photodiodes in the array were masked with a sheet of black rubber. The APD's were biased at the nominal voltage $V_b = 380$ V. Measurements were carried out by irradiating the photodiode with, a): only the light beam emitted from bundle A [see Fig. 5(c)] corresponding to a measured signal intensity S_A at the output of the readout circuit of Fig. 2, b): the light from bundle B corresponding to an intensity S_B , and c): simultaneous irradiation by the two beams corresponding to a measured signal intensity S_{tot} [Fig. 5(b)]. Any saturation in the photodiode or preamplifier would lead to the $S_{\rm tot}$ value being smaller than the expected sum $S_A + S_B$. In Fig. 6 the measured fraction $S_{\text{tot}}/(S_A + S_B)$ at various sums $S_A + S_B$ of the driver amplifier output (Fig. 2) in pC are shown for each photodiode type. Both p-i-n photodiode-amplifier combinations remained linear up to $S_A + S_B \sim 200$ pC. Any residual nonlinearity is primarily caused by the transimpedance and buffer amplifiers. The APD's on the other hand saturated at a signal output of > 40 pC, presumably due to space-charge effects in the depletion region of the APD reducing the effective gain.

3. Measurements

3.1. Relative light yields of Cherenkov radiators

The schematic layout of the experimental setup used to measure the relative light yields Γ of the Cherenkov radiators against antiproton annihilations are shown in Fig. 7 [36, 37]. The AD provided a 200 ns long pulsed beam containing $N_{\overline{p}} = (2-3) \times 10^7$ antiprotons with a kinetic energy E = 5.3 MeV and repetition rate $f \sim 0.01$ Hz. The beam was transported along an evacuated beamline. About 25%of the beam was decelerated to E = 75 keV by allowing the antiprotons to pass through a radiofrequency quadrupole decelerator (RFQD). A momentum analyzer beamline selected the E = 75 keV antiprotons and transported them to a cryogenic target chamber filled with helium gas. The antiprotons came to rest in the helium or metallic walls of the target chamber and underwent nuclear absorption and annihilation. Past experiments show (see Ref. [7] and references therein) that on average some 1.5 π^+ mesons, 1.8 π^- mesons, and 2 π^0 mesons emerge from a $\overline{p} + {}^4\text{He}$ annihilation, and that the momentum of most of the pions are distributed between p = 0.1 and 0.9 GeV/c. The π^0 mesons preferentially decay into two γ rays while still inside the target. The annihilations also lead to fission of the target nuclei, and the emission of fast and slow neutrons.

A single β -PbF₂ crystal was oriented so that either its short (indicated by position 1 in Fig. 7) or long (po-

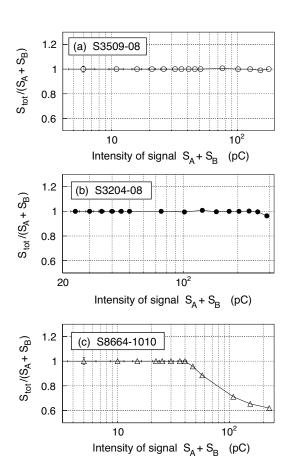


Figure 6: Linearity responses of the p-i-n photodiodes (a) S3590-08 and (b) S3590-08, and (c) the APD S8664-1010 combined with the transimpedance preamplifiers shown schematically in Fig. 2 measured using a LED light source, see text.

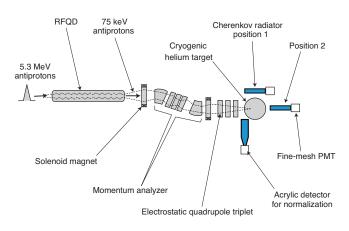


Figure 7: Experimental layout used to measure the responses of Cherenkov radiators against antiproton annihilations (not to scale). Dashed lines show the trajectory of the antiproton beam. The antiprotons were decelerated to E = 75 keV by allowing them to pass through a radiofrequency quadrupole decelerator (RFQD). A momentum analyzer beamline selected the 75 keV antiprotons and transported them to a cryogenic target chamber filled with helium gas. The Cherenkov radiators were placed at two locations indicated by positions 1 and 2. A separate acrylic Cherenkov radiator read out by a fine-mesh photomultiplier tube was used to measure the intensity of the antiproton beam and normalize the data, see text.

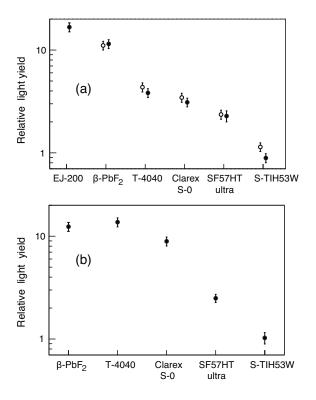


Figure 8: Relative light yields of various Cherenkov radiators against antiproton annihilations measured by placing the detector at the two positions 1 (a) and 2 (b) indicated in Fig. 7. The radiators include lead fluoride (β -PbF₂), fused silica (T-4040), UV transparent acrylic (Clarex S-0), lead glass (SF57HTultra) and lead-free high refractive index glass (S-TIH53W). For the light yields measured at position 1, no significant differences were seen between detector configurations with (indicated by open circles) and without (filled circles) a silicone light coupler placed between the radiator and a finemesh photomultiplier, see text. The light yield of a plastic scintillator (EJ-200) is also shown.

sition 2) axis aligned towards the center of the experimental target at a distance ~ 150 mm. The Cherenkov light produced in the crystal by the antiproton annihilations were measured by a fine-mesh photomultiplier tube (Hamamatsu Photonics R5505G-ASSY) [7] with a bialkali photocathode of diameter d = 17.5 mm and an entrance window made of borosilicate glass. The photomultiplier had a quantum efficiency of > 20% at wavelengths $\lambda = 380{-}440$ nm. The measurements were repeated for the fused silica, acrylic, lead glass, and S-TIH53W glass radiators, and a plastic scintillator (Eljen EJ-200) of the same size. The photon yields at position 1 were measured with and without a transparent $t_d = 5$ mm thick disk made of a two-component silicone rubber (Shinetsu Silicone CAT-103 and KE-103) inserted between the radiator and the entrance window of the photomultiplier to improve the optical coupling. The relative intensity of each antiproton pulse was normalized using the readout of a second Cherenkov detector of size $480 \text{ mm} \times 160 \text{ mm} \times 20$ mm made of UV-transparent acrylic (Mitsubishi Rayon, Acrylite000). The detector was positioned 400 mm away from the target, so that the solid angle seen from the target

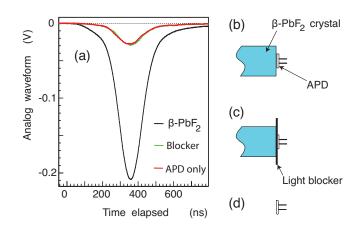


Figure 9: (a) Black curve indicates the signal waveform of antiproton annihilations measured by reading out the β -PbF₂ radiators with APD's as shown schematically in (b). It corresponds to the temporal profile of the 400 ns long pulsed antiproton beam. The green curve shows the NCE waveform measured by using a rubber sheet to prevent the Cherenkov light from reaching the APD as shown in (c). The red curve which is partially overlapping with the green one, corresponds to the waveform measured using only the APD without any radiator (d), see text.

was $\sim 1\%$.

The relative light yields Γ of the five radiators and plastic scintillator measured at position 1 are compared in Fig. 8(a). Each data point represents the average of measurements collected over 30 antiproton pulses, using three samples of each radiator type. The β -PbF2 crystals showed the highest light yield that was a factor three larger than the Γ values of the fused silica and acrylic radiators. This is due to the short radiation length and high refractive index of β -PbF2 that allowed the efficient detection of γ -rays and low-momentum pions. Primarily because of the low transparencies at short wavelengths, the lead glass and S-TIH53W radiators showed light yields that were factors of 5 and 10 smaller compared to β -PbF₂, respectively. No significant differences were seen between the Γ -values measured with (indicated by open circles) and without (filled circles) the silicone light coupler placed between the radiators and photomultiplier.

Fig. 8(b) shows the light yields measured with the five radiator types placed at position 2. The Γ -values of the fused silica and β -PbF₂ radiators are now approximately equal, despite the factor ~ 13 shorter radiation length of the latter material. This is believed to be due to the lower transparency of β -PbF₂ compared to fused silica which results in the absorption of a significant number of those UV Cherenkov photons that were produced in the part of the crystal closest to the experimental target, that prevent them from reaching the photomultiplier.

3.2. Nuclear counter effects

We next studied the nuclear counter effect (NCE) caused by secondary particles traversing the readout photodiodes. For this the β -PbF₂ array of Fig. 1 was positioned at a distance ~ 550 mm from the cryogenic helium target, with

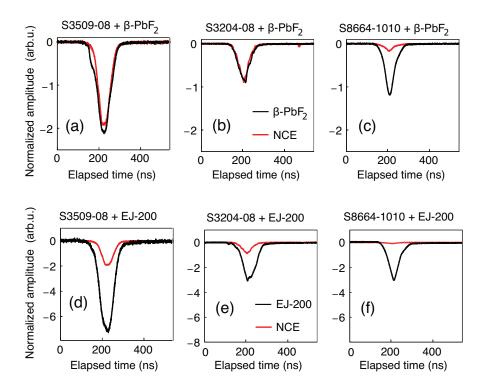


Figure 10: Signal waveforms of various detectors measuring antiproton annihilations in the helium target. Black curves represent the waveforms of the *p-i-n* photodiodes (a) S3509-08 and (b) S3204-08, and (c) the APD S8664-1010 coupled to a β -PbF₂ radiator array. The NCE waveforms measured using only the photodiodes without the radiator are plotted using red curves that are superimposed on each spectrum. Signal and NCE waveforms of the light output of a plastic scintillator array read out by (d) S3509-08, (e) S3204-08, and (f) S8664-1010 photodiodes, see text.

the short axis of the crystals aligned towards the direction where the antiprotons annihilated. The AD provided a 400 ns long antiproton beam. The black curve of Fig. 9(a)shows the analog waveform of the signal obtained by reading out the β -PbF₂ crystals using APD's, and averaging the data accumulated over 10 consecutive arrivals of antiproton pulses at the target. A schematic drawing of one of the five crystal-APD connections in the array is shown in Fig. 9(b). The APD's were biased at a voltage $V_b = 380$ V. The signal is a superposition of the flash of Cherenkov light in the crystal and the NCE, and shows the temporal profile of the beam. To roughly estimate the contribution of the NCE, the measurement was repeated with a black rubber sheet placed between the crystals and the APD's to prevent the Cherenkov photons from reaching the APD's [Fig. 9(c)]. The measured waveform [indicated by the green curve of Fig. 9(a)] shows that $\sim 15\%$ of the detector signal arises from the NCE. The measurement was repeated with the β -PbF₂ crystals removed from the detector. No significant change [red curve of Fig. 9(a)] was seen compared to the measurement with the rubber sheet. This indicates that the effect of the crystals shielding the APD's from secondary particle hits was relatively small under the geometric layout of the experiment.

We next repeated the measurements by using the S3509-08 and S3204-08 p-i-n photodiodes as well as the APD's to read out the five β -PbF₂ crystals. The resulting waveforms are shown using black curves in Figs. 10(a)-(c). The pulse duration of the antiproton beam was reduced to $\Delta t \sim 200$ ns during these measurements. Each waveform represents the average of data collected from five antiproton pulses. The signal was normalized against the intensity of the antiproton beam which was measured using a separate acrylic Cherenkov detector read out by a fine-mesh photomultiplier tube. The NCE waveforms of each photodiode type measured by removing the β -PbF₂ crystals are shown superimposed using red curves. The fact that the amplitudes of the p-i-n photodiode waveforms measured with and without the crystals are similar shows that most of the detector signal arises from the NCE. This agrees with the results of Monte-Carlo simulations [40] that indicate that each pion hit on a p-i-n photodiode predominantly produced > 20000 ion-electron pairs, compared to an estimated few hundred photoelectrons collected per hit on the Cherenkov radiator. The amplitude of the NCE waveform was proportional to the number of antiproton annihilations. The NCE effectively restricted the sensitive volume of the detector against charged pion and γ -ray hits

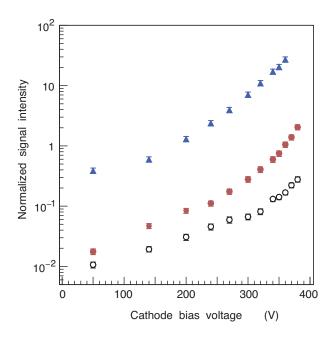


Figure 11: Signal intensities of β -Pb F_2 Cherenkov radiators read out by APD's normalized to the intensity of the antiproton beam, as a function of the bias voltage applied to the APD (filled rectangles). Signal intensities of the plastic scintillator array read out by APD's (triangles). NCE intensities obtained using only the APD without any radiator (open circles).

to the ~ 0.3–0.5 cm³ depletion regions in the photodiodes, instead of the full 720 cm³ volume of the β -PbF₂ crystal array. The measurements of the antiproton annihilations were repeated using the EJ-200 plastic scintillator array. The signal waveforms of the scintillators read out by the three types of photodiodes are plotted in Figs. 10(d)–(f) using black curves. In the case of the *p-i-n* photodiode, the NCE contribution [red curves of Figs. 10(d)–(e)] corresponded to ~ 25% of the total signal.

Fig. 11 shows the relative intensities of the APD signals against antiproton annihilations, measured at bias voltages between $V_b = 50$ V and 400 V. Each data point corresponds to the average of data collected from five antiproton pulses, which were normalized against the intensity of the antiproton beam measured using the acrylic Cherenkov detector. Measurements were carried out with (indicated by closed circles) and without (open circles) a β -PbF₂ radiator crystal coupled to the APD. At low bias voltages $V_b = 50$ V which corresponded to an APD gain near unity, the NCE constituted > 60% of the total signal. At higher bias $V_b = 380$ V corresponding to a APD gain $g \ge 80$, the relative intensity of the NCE was reduced to $\sim 15\%$ of the Cherenkov detector signal as mentioned above. A similar tendency of smaller relative NCE at higher gain was seen for APD's reading out plastic scintillators (indicated in Fig. 11 by triangles), though some saturation in the signal was seen at $V_b \ge 320$ V. At a bias $V_b = 380$ V, the NCE corresponded to $\sim 2\%$ of the total signal, as shown in the signal waveforms of Fig. 10(f).

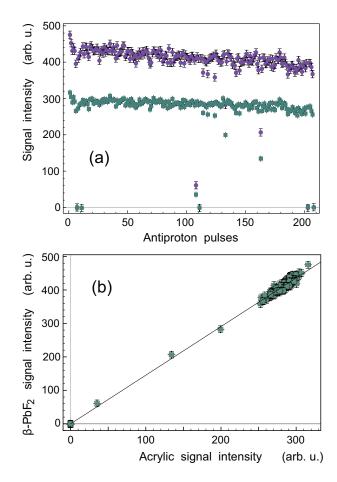


Figure 12: (a) Relative intensities of 205 antiproton pulses arriving at the cryogenic helium target, measured using an array of β -PbF₂ Cherenkov radiators read out by APD's (filled circles) and an acrylic radiator read out by a fine-mesh photomultiplier tube (squares). (b) Correlation between the signal intensities of the two Cherenkov detectors.

3.3. Antiproton beam intensity

Fig. 12(a) shows the relative intensities of 205 antiproton pulses that were decelerated by the RFQD to energy E = 75 keV over a 8 h period, measured using the β -PbF₂ Cherenkov detector array read out by APD's (indicated by filled circles). A bias voltage $V_b = 380$ V was used. We simultaneously measured the response of the acrylic Cherenkov detector read out by a fine-mesh photomultiplier (filled squares), which is known to be highly linear at these beam intensities [7]. The shot-to-shot fluctuations seen here were primarily caused by variations in the number of antiprotons that were created in the production target of the AD. The correlation between the intensity measurements made by the two detectors [Fig. 12(b)] indicates that the linearity of the β -PbF₂ Cherenkov detector array is better than 5%. The residual nonlinearity is assumed to be mostly due to the contribution of the NCE and the response of the APD at high light intensities. Time- and temperature-dependent shifts in the APD gain were estimated to be of order $\sim 2\%$.

Fig. 13 shows the layout of an experiment [3] employing

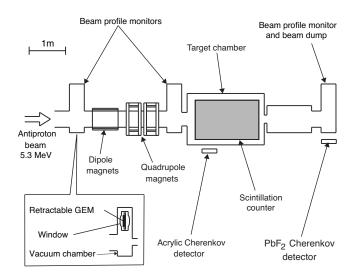


Figure 13: Experimental layout to measure the cross section σ_{tot}^A of antiprotons with a kinetic energy E = 5.3 MeV annihilating in a carbon target (not to scale) [3]. A pulsed antiproton beam was allowed to traverse a target chamber that contained a thin carbon target. The small number of annihilations that occurred in the target was measured by a scintillation counter. The rest of the antiprotons struck a profile monitor based on gas electron multipliers (GEMs) located at the end of the experimental setup. The β -PbF₂ Cherenkov detector was positioned 300 mm away from the GEM detector. The short axis of the crystals was aligned towards the direction of the position where the antiprotons annihilated.

the β -PbF₂ Cherenkov detector, in which the total cross section of antiprotons with kinetic energy E = 5.3 MeV annihilating in a carbon target was measured. In the experiment, radiofrequency cavities were first used to bunch the $(2-4) \times 10^7$ antiprotons circulating in the AD into six pulses which were distributed equidistantly around its 190 m-circumference. These pulses of length $\Delta t \sim 50$ ns were then sequentially extracted to the experiment at intervals of ~ 2.4 s, by exciting a kicker magnet located within the AD. The beam was focused by a quadrupole doublet before entering a 3-m long vacuum chamber containing a diamond-like carbon target with a thickness of either $t_d = 0.7$ or 1.0 μ m. Between 1 and 10 annihilations occurred via in-flight nuclear reactions for every 10^6 antiprotons traversing the target foil. The remaining antiprotons emerged from the other side of the foil, traversed a 2 m long section of evacuated beam pipe, and stuck a profile monitor based on gas electron multipliers (GEMs) located at the end of the experiment. This GEM detector was mounted inside the vacuum pipe of the beamline, and functioned as a beam dump where all the antiprotons annihilated. The β -PbF₂ Cherenkov detector was positioned 300 mm away from the GEM detector, with the short axis of the crystals aligned toward the annihilation position of the antiprotons. The relative intensity of the antiproton beam measured by the β -PbF₂ detector was used to appropriately normalize the annihilation counts measured by the scintillation counter to obtain the cross section. Further details and the results of the experiment are provided

in Ref. [3].

4. Discussions and Conclusions

In conclusion, we have constructed a Cherenkov detector consisting of an array of five β -PbF₂ crystals of size $30 \text{ mm} \times 30 \text{ mm} \times 160 \text{ mm}$ read out by APD's. The detector was used to measure the flux of secondary particles (mostly charged pions and γ rays) emerging from the annihilations of high-intensity antiproton beams. When the radiators were positioned so that the majority of the secondary particles entered the radiator in the direction parallel to its short axis, the light yield of the β -PbF₂ crystals measured with a bialkali photomultiplier tube was a factor > 2-3 higher compared to acrylic and glass radiators of the same size. When the secondary particles traversed the long axis of the radiators, however, the light yields of the β -PbF₂ and fused silica radiators became approximately equal. This is presumably caused by the lower UV transmission of β -PbF₂ compared to fused silica. Cherenkov radiators read out using p-i-n photodiodes showed output signals that mostly consisted of the contribution from the nuclear counter effect (NCE) of secondary particles striking the photodiodes. APD's were less affected by the NCE, so that its contribution in the case of β -PbF₂ readout was $\sim 15\%$ of the total signal in the experimental setup used by us. The *p-i-n* photodiode and APD readout of plastic scintillators showed that the NCE contribution was $\sim 25\%$ and $\sim 2\%$ for the two photodiode cases, respectively. We used the β -PbF₂ Cherenkov radiators read out by APD's in a recent measurement to determine the cross section of antiprotons with kinetic energy E = 5.3 MeV annihilating in carbon targets.

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